

描述 / Descriptions

SOT-23 塑封封装 PNP 半导体三极管。Silicon PNP transistor in a SOT-23 Plastic Package.

特征 / Features

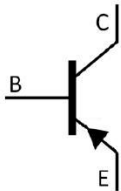
低电流，低电压，小封装。

Low current ,Low voltage ,S-mini package.

用途 / Applications

用于一般放大

General power amplifier application.

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN1 : Base PIN 2 : Emitter PIN 3 : Collector

放大及印章代码 / h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	A	B
h_{FE} Range	125~250	220~475
Marking	H3A	H3B

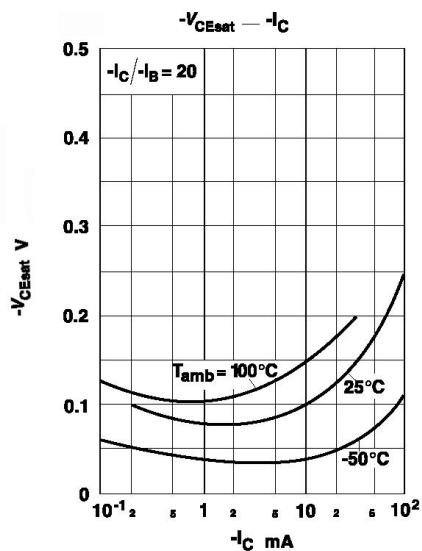
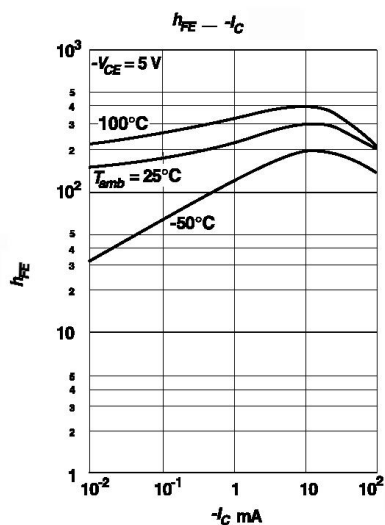
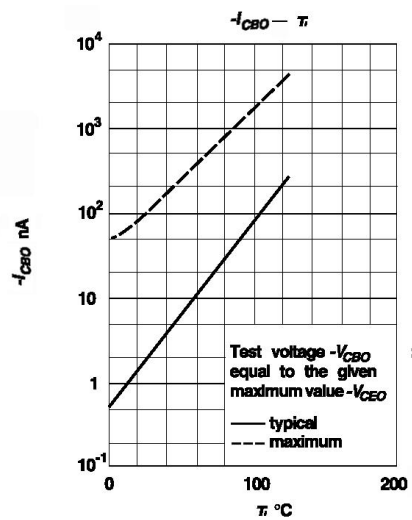
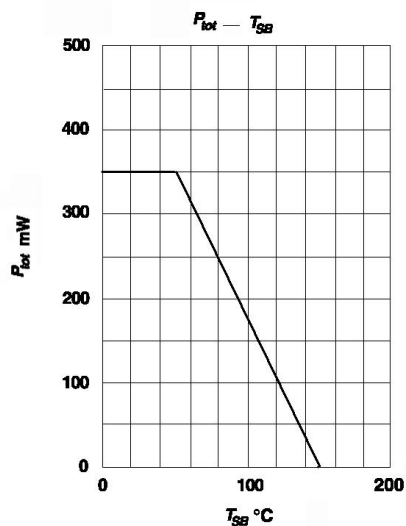
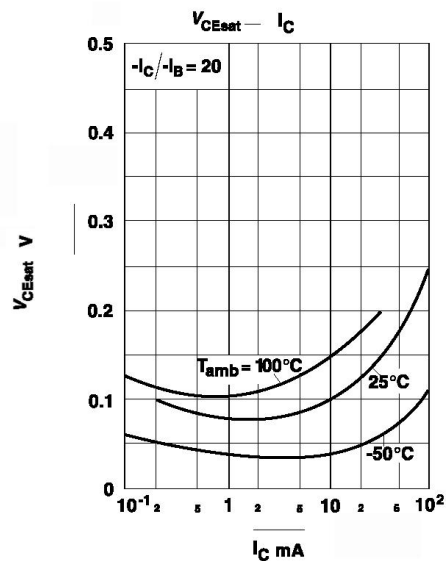
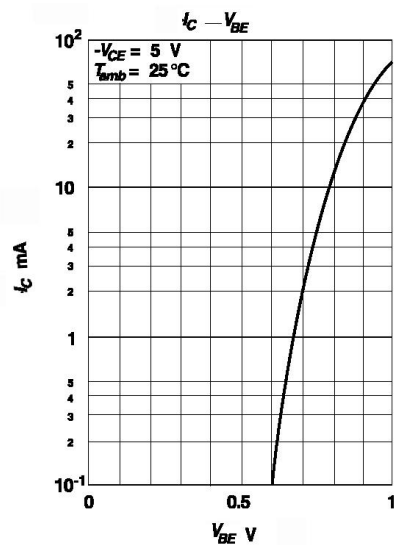
极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Collector to Base Voltage	V_{CBO}	-80	V
Collector to Emitter Voltage	V_{CEO}	-65	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-100	mA
Collector Power Dissipation	P_C	350	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-30\text{ V}$ $I_E=0$			-0.015	μA
DC Current Gain	h_{FE}	$V_{CE}=-5.0\text{V}$ $I_C=-2.0\text{mA}$	125		475	
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=-10\text{mA}$ $I_B=-0.5\text{mA}$		-0.09	-0.3	V
	$V_{CE(sat)(2)}$	$I_C=-100\text{mA}$ $I_B=-5.0\text{mA}$		-0.25	-0.65	V
Base to Emitter Saturation Voltage	$V_{BE(sat)(1)}$	$I_C=-10\text{mA}$ $I_B=-0.5\text{mA}$		-0.7		V
	$V_{BE(sat)(2)}$	$I_C=-100\text{mA}$ $I_B=-5.0\text{mA}$		-0.9		V
Base to Emitter Voltage	$V_{BE(ON)1}$	$V_{CE}=-5.0\text{V}$ $I_C=-2.0\text{mA}$	-0.6	-0.65	-0.75	V
Base to Emitter Voltage	$V_{BE(ON)2}$	$V_{CE}=-5.0\text{V}$ $I_C=-10\text{mA}$			-0.82	V
Transition Frequency	f_T	$V_{CE}=-5.0\text{V}$ $I_C=10\text{mA}$ $f=100\text{MHz}$		150		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}$ $I_E=0$ $f=1.0\text{MHz}$		4.5		pF
Noise Figure	NF	$V_{CE}=-6.0\text{V}$ $I_C=-0.1\text{mA}$ $R_g=2\text{K}\Omega$ $f=1.0\text{KHz}$		2.0	10	dB

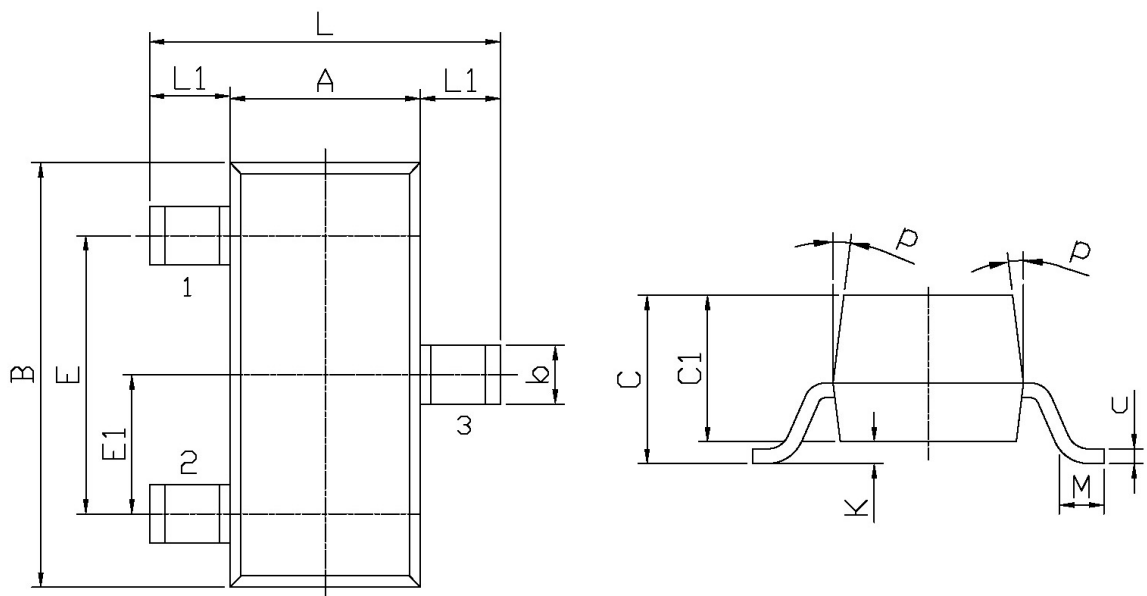
电参数曲线图 / Electrical Characteristic Curve



外形尺寸图 / Package Dimensions

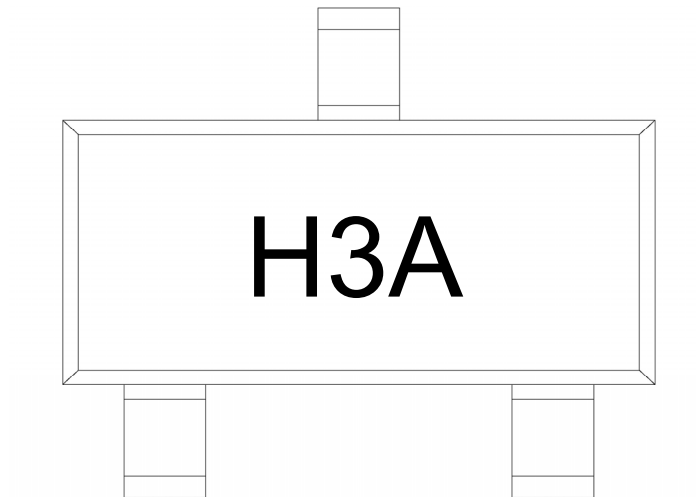
SOT-23

单位: mm



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.2	2.7	C	1.30Max	
L1	0.45	0.65	C1	0.90	1.20
A	1.15	1.50	c	0.05	0.20
B	2.70	3.10	K	0	0.10
E	1.70	2.10	M	0.20MIN	
E1	0.85	1.05	P	7°	
b	0.35	0.55			

印章说明 / Marking Instructions



说明：

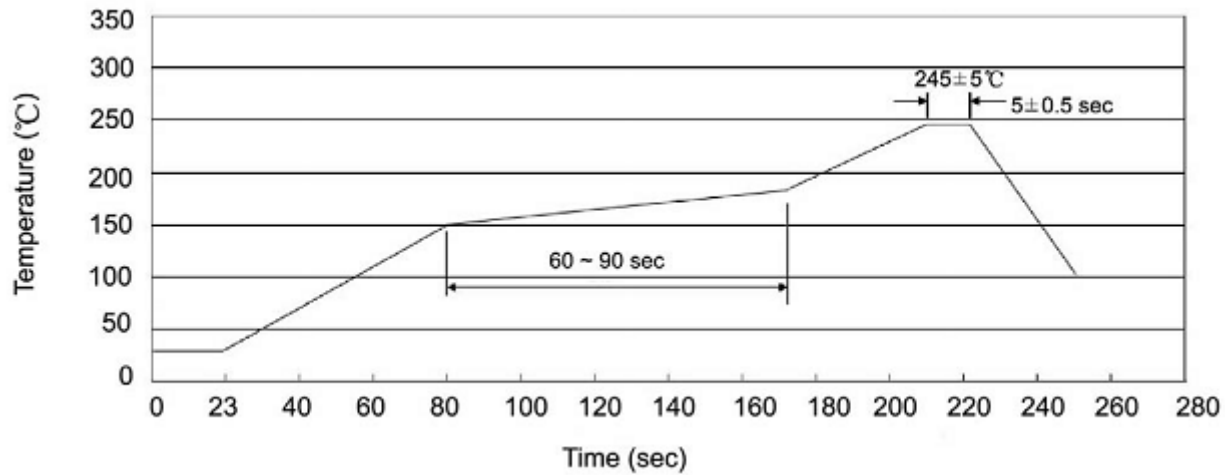
H： 为公司代码

3A： 为型号代码

Note:

H: Company Code.

3A: Product Type Code

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)


说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7" x8	180×120×180	390×385×205

使用说明 / Notices